

ULTRA FAST RECOVERY RECTIFIER DIODES



Glass-passivated, high-efficiency epitaxial rectifier diodes in DO-4 metal envelopes, featuring low forward voltage drop, ultra fast reverse recovery times, very low stored charge and soft recovery characteristic. They are intended for use in switched-mode power supplies and high-frequency circuits in general, where low conduction and switching losses are essential. The series consists of normal polarity (cathode to stud) types.

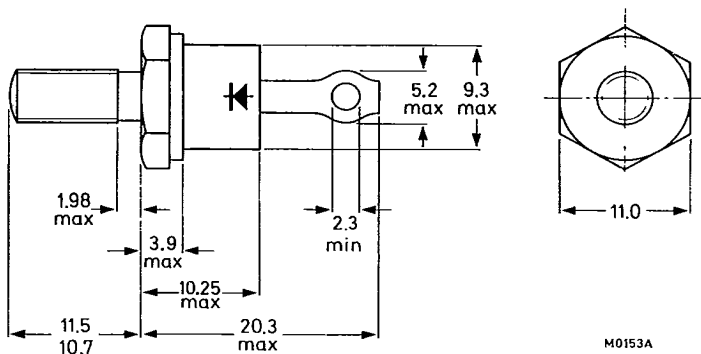
QUICK REFERENCE DATA

		BYW31-50				
		100	150	200		
Repetitive peak reverse voltage	V_{RRM}	max. 50	100	150	200	V
Average forward current	$I_{F(AV)}$	max. 28				A
Forward voltage	V_F	< 0.8				V
Reverse recovery time	t_{rr}	< 40				ns

MECHANICAL DATA

Dimensions in mm

Fig.1 DO-4; with metric M5 stud ($\phi 5$ mm); e.g. BYW31-50.
with 10-32 UNF stud ($\phi 4.83$ mm); e.g. BYW31-50U.



Net mass: 7 g

Diameter of clearance hole: max. 5.2 mm

Accessories supplied on request:
see ACCESSORIES section.

Supplied with device: 1 nut, 1 lock washer

Torque on nut: min. 0.9 Nm (9 kg cm)
max. 1.7 Nm (17 kg cm)

Nut dimensions across the flats;
M5: 8.0 mm; 10-32 UNF: 9.5 mm

Products approved to CECC 50 009-002, available on request.

T-03-19

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134).

Voltages

		BYW31-50	100	150	200	
Repetitive peak reverse voltage	V_{RRM}	max. 50	100	150	200	V
Crest working reverse voltage	V_{RWM}	max. 50	100	150	200	V
Continuous reverse voltage*	V_R	max. 50	100	150	200	V

Currents

Average forward current; switching

losses negligible up to 500 kHz
square wave; $\delta = 0.5$; up to $T_{mb} = 122\text{ }^\circ\text{C}$
up to $T_{mb} = 125\text{ }^\circ\text{C}$

$I_F(AV)$	max.	28	A
$I_F(AV)$	max.	26	A

sinusoidal; up to $T_{mb} = 127\text{ }^\circ\text{C}$

$I_F(AV)$	max.	25	A
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R.M. S. forward current

$I_F(RMS)$	max.	40	A
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Repetitive peak forward current

$t_p = 20\text{ }\mu\text{s}$; $\delta = 0.02$

I_{FRM}	max.	550	A
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Non-repetitive peak forward current

half sine-wave; $T_j = 150\text{ }^\circ\text{C}$ prior to surge;
with reapplied V_{RWMmax} ;

$t = 10\text{ ms}$

$t = 8.3\text{ ms}$

I_{FSM}	max.	320	A
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I_{FSM}	max.	380	A
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I^2t for fusing ($t = 10\text{ ms}$)

I^2t	max.	500	A^2s
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Temperatures

Storage temperature

T_{stg}		-55 to +150	$^\circ\text{C}$
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Junction temperature

T_j	max.	150	$^\circ\text{C}$
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THERMAL RESISTANCE

From junction to mounting base

$R_{th\ j-mb}$	=	1.0	K/W
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From mounting base to heatsink

a. with heatsink compound

$R_{th\ mb-h}$	=	0.3	K/W
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b. without heatsink compound

$R_{th\ mb-h}$	=	0.5	K/W
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Transient thermal impedance: $t = 1\text{ ms}$

$Z_{th\ j-mb}$	=	0.2	K/W
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MOUNTING INSTRUCTIONS

The top connector should be neither bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum.

*To ensure thermal stability: $R_{th\ j-a} \leq 4.9\text{ K/W}$ (continuous reverse voltage).

CHARACTERISTICS

T-03-19

Forward voltage

$I_F = 30 \text{ A}; T_j = 150 \text{ }^\circ\text{C}$
 $I_F = 100 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$

$V_F < 0.8 \text{ V}^*$
 $V_F < 1.3 \text{ V}^*$

Reverse current

$V_R = V_{RWM \text{ max}}; T_j = 100 \text{ }^\circ\text{C}$
 $T_j = 25 \text{ }^\circ\text{C}$

$I_R < 1.5 \text{ mA}$
 $I_R < 100 \text{ } \mu\text{A}$

Reverse recovery when switched from

$I_F = 1 \text{ A to } V_R \geq 30 \text{ V}$ with $-dI_F/dt = 100 \text{ A}/\mu\text{s}$;
 $T_j = 25 \text{ }^\circ\text{C}$; recovery time

$t_{rr} < 40 \text{ ns}$

$I_F = 2 \text{ A to } V_R \geq 30 \text{ V}$ with $-dI_F/dt = 20 \text{ A}/\mu\text{s}$;
 $T_j = 25 \text{ }^\circ\text{C}$; recovered charge

$Q_s < 20 \text{ nC}$

$I_F = 10 \text{ A to } V_R \geq 30 \text{ V}$ with $-dI_F/dt = 50 \text{ A}/\mu\text{s}$;
 $T_j = 100 \text{ }^\circ\text{C}$; peak recovery current

$I_{RRM} < 4 \text{ A}$

Forward recovery when switched to $I_F = 10 \text{ A}$
 with $dI_F/dt = 10 \text{ A}/\mu\text{s}; T_j = 25 \text{ }^\circ\text{C}$

$V_{fr} \text{ typ. } 1 \text{ V}$

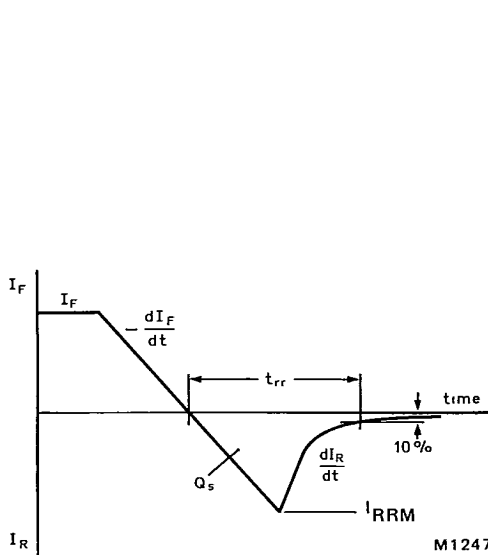


Fig.2 Definition of t_{rr} , Q_s and I_{RRM} .

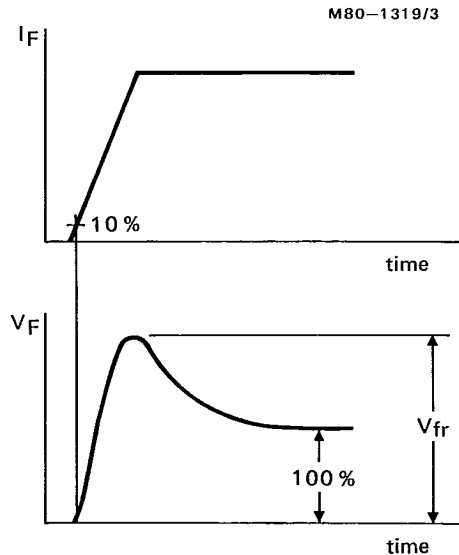


Fig.3 Definition of V_{fr} .

*Measured under pulse conditions to avoid excessive dissipation.

SQUARE-WAVE OPERATION

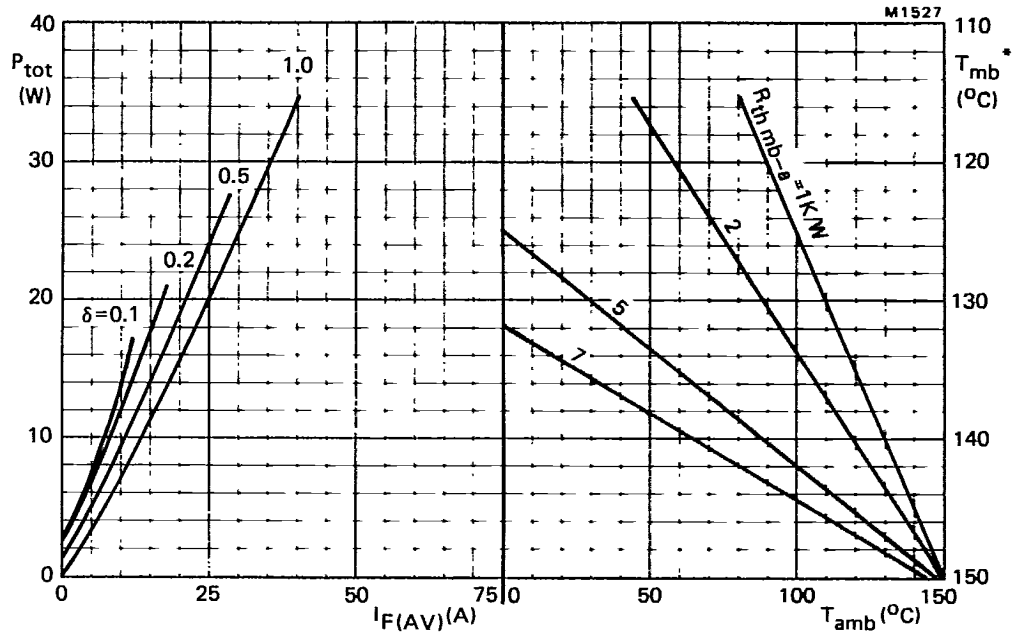
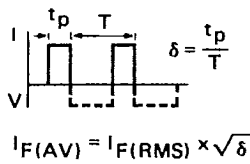


Fig.4 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures. Power includes reverse current losses and switching losses up to $f = 500$ kHz.



* T_{mb} scale is for comparison purposes and is correct only for $R_{th mb-a} < 3.6 K/W$.

SINUSOIDAL OPERATION

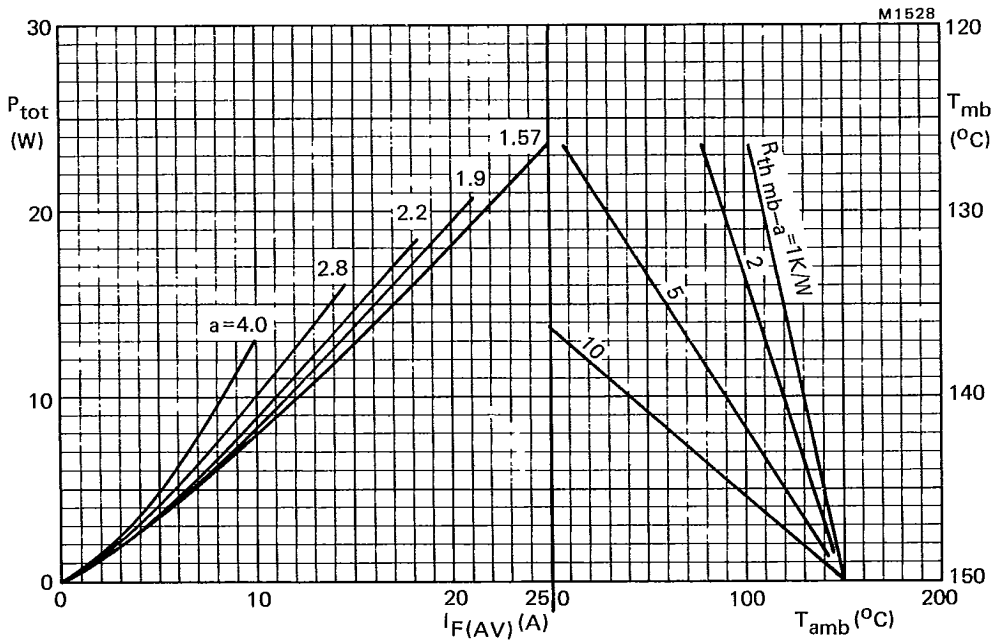


Fig.5 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures. Power includes reverse current losses and switching losses up to $f = 500$ kHz.

$a = \text{form factor} = I_F(RMS)/I_F(AV)$.

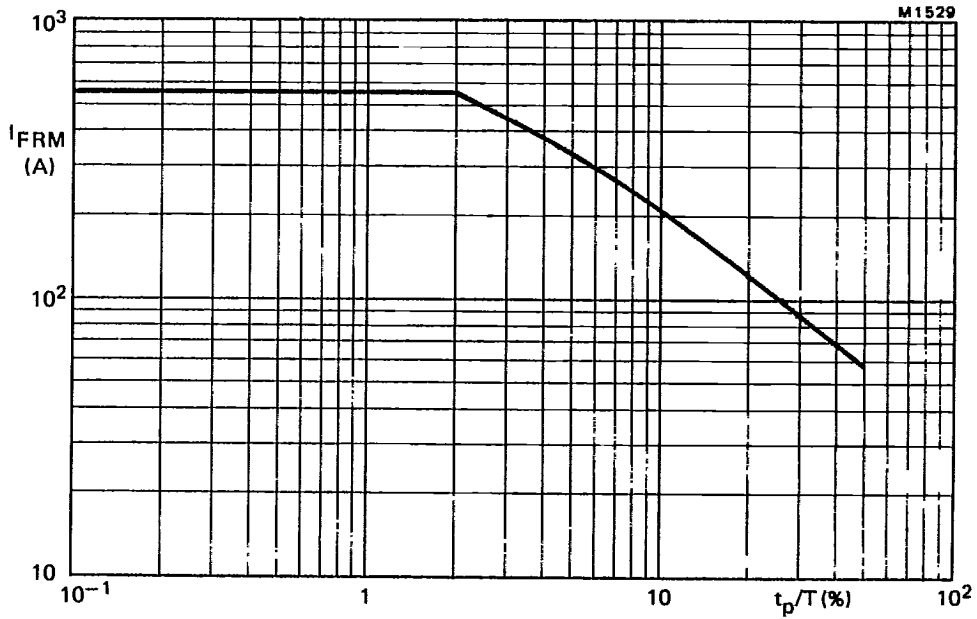
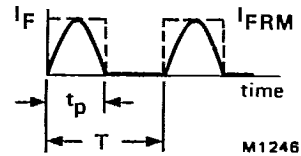
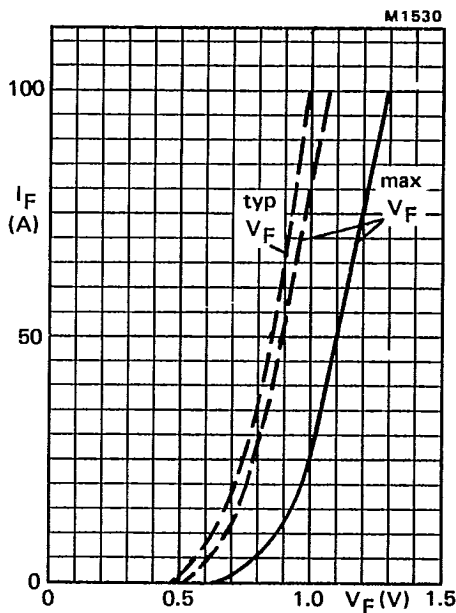


Fig.6 Maximum permissible repetitive peak forward current for square or sinusoidal currents; $1 \mu s < t_p < 1 \text{ ms}$.



Definition of I_{FRM} and t_p/T .

Fig.7 ——— $T_j = 25 \text{ }^\circ\text{C}$; - - - $T_j = 150 \text{ }^\circ\text{C}$.

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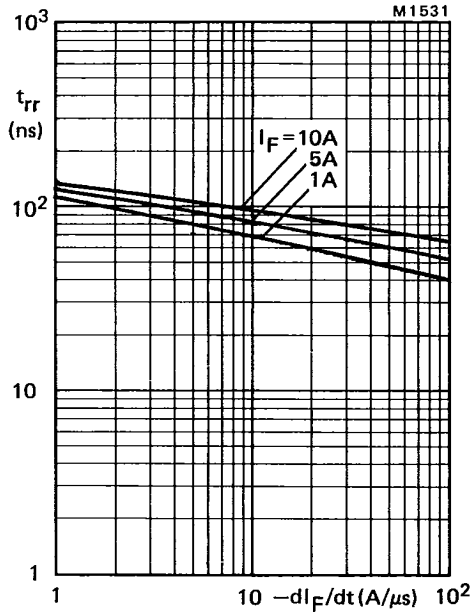


Fig.8 Maximum t_{rr} at $T_j = 25\text{ }^\circ\text{C}$.

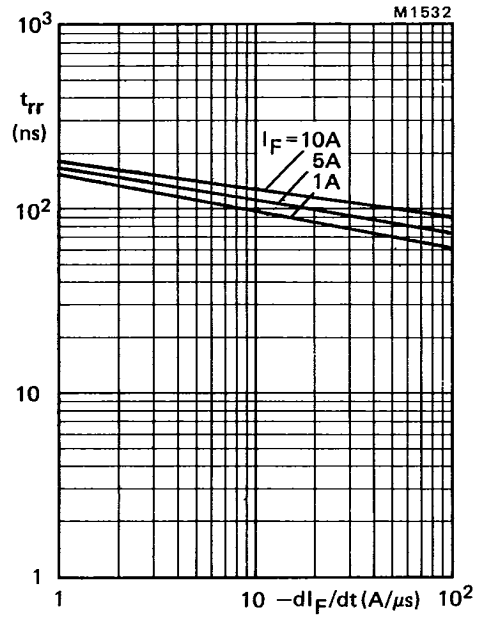


Fig.9 Maximum t_{rr} at $T_j = 100\text{ }^\circ\text{C}$.

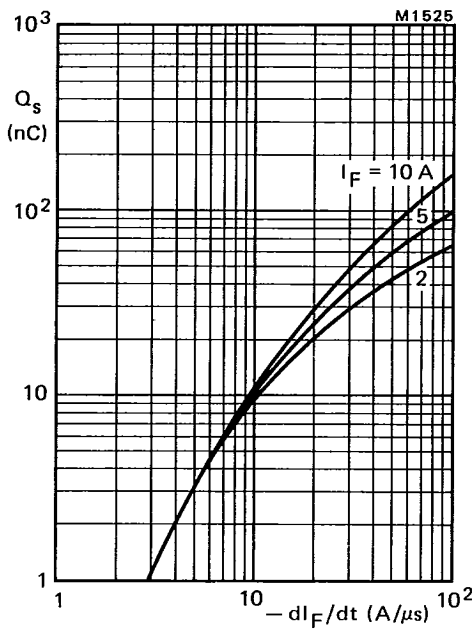


Fig.10 Maximum Q_s at $T_j = 25\text{ }^\circ\text{C}$.

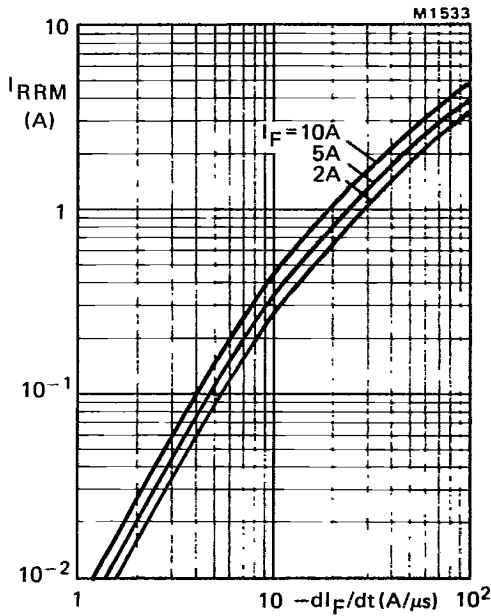


Fig.11 Maximum I_{RRM} at $T_j = 25$ °C.

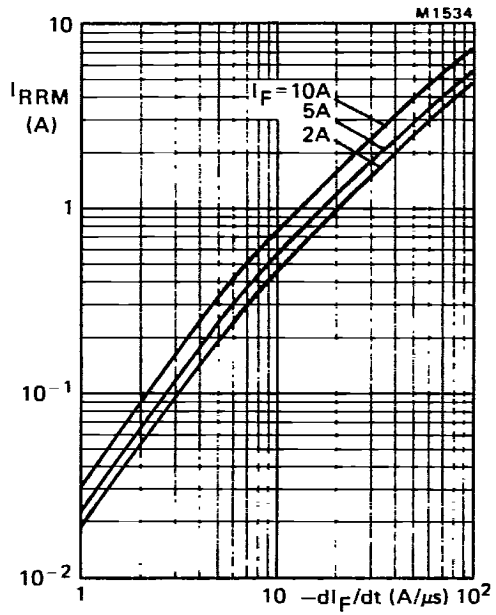


Fig.12 Maximum I_{RRM} at $T_j = 100$ °C.

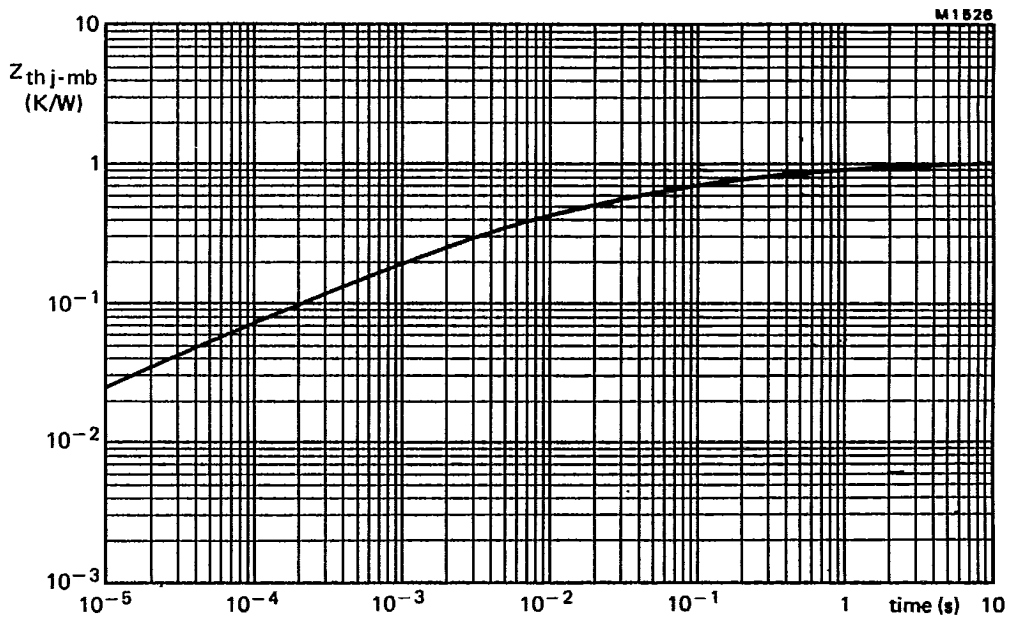


Fig.13 Transient thermal impedance.